## NSN 5961-01-381-7429

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-381-7429 **Inclosure Material:** Glass **Overall Length:** Between 0.125 inches and 0.250 inches **Terminal Length:** Between 0.700 inches and 1.300 inches **Overall Diameter:** Between 0.065 inches and 0.085 inches **Mounting Method:** Terminal **Features Provided:** Burn in and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 nonrepetitive peak reverse voltage and 400.0 working peak reverse voltage and 400.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 2.00 amperes forward current, average **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/585 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: